A New Unterminating Method for De-Embedding the Coaxial to Waveguide Transitions

Stefan Simion

Abstract—A new unterminating method for coaxial to waveguide transitions is presented. The coaxial to waveguide transitions are modelled, and the ABCD matrices of the transitions are obtained. The measured scattering parameters for the thru and short-circuit calibration standards match well the simulated scattering parameters computed from the ABCD matrices. To complete the validation of the proposed unterminating method, this method is applied to the measurement of complex relative permittivity for three different dielectric materials, by using the Nicolson-Ross-Weir (NRW) transmission/reflection method. The dielectric samples are inserted one by one into a waveguide section, which is connected between two coaxial to waveguide transitions. The two transitions are de-embedded from the measured scattering parameters of the embedded waveguide section, by using the method proposed in this paper. The values obtained for the complex relative permittivity are in good agreement with those reported by other authors, for all three dielectric materials. The results presented in this paper were obtained for a frequency band ranging from 25 to 40 GHz.

1. INTRODUCTION

Because Vector Network Analyzers (VNAs) use coaxial connectors, transitions from coaxial to microstrip lines and waveguides, as well as from coaxial to the circuit pads used for on-wafer measurements, have been analyzed and used in practice (see for example [1-6] and [7-9], respectively). In all cases, VNA measures the scattering (S-) parameters of the embedded device under test. To obtain S-parameters of the device under test, the intervening transitions must be de-embedded from the S-parameters measured at the VNA reference ports. To do this, the frequency behavior of the transitions must be analyzed experimentally, this process being known as unterminating [10,11]. Based on the measurements performed for different calibration standards, two-port parameters of the transitions can be determined [6-14].

Referring to the commercial coaxial to waveguide transitions, these are microwave components that are used as the only way to connect waveguide devices to the VNA reference ports. If the waveguide calibration standards are not available for VNA calibration at the waveguide ports, the coaxial to waveguide transition must be de-embedded, so that an unterminating technique must be used. An algorithm which minimizes the errors between the measured and simulated S-parameters for different standards has been proposed in [6] as an unterminating technique for such a transition. The method used in this work is accurate, but laborious and time consuming.

In this paper, a new noniterative unterminating technique for the coaxial to waveguide transition is proposed. It is based on the S-parameters obtained by only two measurements, performed for thru and short-circuit calibration standards, without assuming that the transitions connected to the VNA reference ports are identical. Based on the proposed method, the ABCD matrices of the transitions are obtained.
The unterminating method is validated in two steps. The first step is to compare the measured $S$-parameters for the thru and short-circuit standards with the simulated ones obtained from the $ABCD$ matrices of the transitions. In the second step of the validation of the unterminating method, the complex relative permittivity values for different dielectric materials are determined using the Nicolson-Ross-Weir (NRW) method [15, 16] for a waveguide test configuration and compared to the values reported by other authors. The NRW method is commonly used for coaxial test fixture configurations [15–22], where de-embedding process is not required. Compared to the coaxial test fixture, the dielectric sample can be inserted or removed more easily, and the air gap around the sample can be greatly reduced in the case of waveguide configuration. ABS (acrylonitrile butadiene styrene), PLA (polylactic acid), and PTFE (polytetrafluoroethylene) materials were used to realize the dielectric samples for which their complex relative permittivities are determined in this paper.

The paper is organized as follows. In Section 2, the unterminating method proposed for the coaxial to waveguide transitions is described in detail. In Section 3, the measured scattering parameters are compared with those obtained from the $ABCD$ matrices of the transitions, which are developed in this paper. The proposed unterminating method is used in Section 4, where the complex relative permittivity values for three different dielectric materials are determined, and a comparison with the results reported in other papers is presented. Conclusions on the results obtained in this paper are drawn in the last section.

2. DESCRIPTION OF THE PROPOSED UNTERMINATING METHOD

The proposed unterminating method is based on two sets of measured $S$-parameters, which are obtained with a VNA at the coaxial ports of the coaxial to waveguide transitions. In the following, the ports of the coaxial to waveguide transitions are named Port #1 and Port #2. VNA is connected to Port #1 and Port #2 using coaxial cables, and the calibration of the VNA is performed at the ends of these coaxial cables which are connected to Port #1 and Port #2.

For the first set of measurements, the waveguide flanges of the coaxial to waveguide transitions $T1$ and $T2$ are connected directly to each other (thru standard), as shown in Fig. 1(a). The proposed equivalent circuit between ports #1 and #2 is shown in Fig. 1(b), where the input two-port circuits $C_{in}$, characteristic impedances $Z_{c1}$ and $Z_{c2}$ of the transmission lines of electrical lengths equal to 90°, as well as the electrical length $\theta$ of the transmission line of characteristic impedance $Z_o$, must be determined (all electrical lengths are computed at the frequency for which the equivalent circuit is determined). Also, $Z_o$ is equal to the wave impedance on the dominant mode $TE_{10}$ of the rectangular hollow metallic waveguides of the transitions, and its value is known as the inner width and height of the rectangular waveguides are known.

Since the measured structure is reciprocal, the scattering parameters $S_{12}$ and $S_{21}$ for the equivalent circuit shown in Fig. 1(b) must be equal. On the other hand, small differences between the measured $S_{12}$ and $S_{21}$ are observed in practice. In the following, $S^{thru}$ is the matrix of $S$-parameters obtained by measurements at the coaxial ports #1 and #2 of the two-port structure shown in Fig. 1, where elements 12 and 21 are equal to each other, and equal to the square root of the product between the measured values of $S_{12}$ and $S_{21}$.

![Figure 1](image-url) (a) Two coaxial to waveguide transitions connected to the waveguide flanges, and (b) the proposed equivalent circuit of this structure.
The matrix $S_{\text{thru}}$ can be transformed into the $ABCD$ matrix $A_{\text{thru}}$, as well as into the impedance matrix $Z_{\text{thru}}$. The measured structure shown in Fig. 1(a) is not lossless, such that the elements of the $Z_{\text{thru}}$ matrix are complex numbers. Because the transmission lines used in the proposed equivalent circuits are lossless, all losses are included into the input circuits $C_{in}$. Here, the transitions are assumed to be identical in terms of losses. In practice, if transitions of the same type are used, the differences between their losses are really very small, so that this hypothesis can be taken into account. If $Z_x$ is the impedance matrix of the lossless two-port consisting of the three lossless transmission lines shown in Fig. 1(b), we may impose that $Z_x$ can be obtained by letting the real parts of the $Z_{\text{thru}}$ matrix elements equal to zero, so that $Z_x = j \text{Im}(Z_{\text{thru}})$. On the other hand, the following expressions can be obtained analytically for the elements of the impedance matrix $Z_x$:

\begin{align}
Z_{11} &= -j Z_{c1}^2 / [Z_o \tan(\theta)], \\
Z_{22} &= -j Z_{c2}^2 / [Z_o \tan(\theta)] \quad \text{and} \\
Z_{12} &= Z_{21} = j Z_{c1} Z_{c2} / [Z_o \sin(\theta)], \\
\end{align}

with all these impedances being imaginary numbers. If $X_{11} = \text{Im}(Z_{11})$, $X_{22} = \text{Im}(Z_{22})$, and $X_{12} = \text{Im}(Z_{12})$, from (1)–(3), $\cos(\theta) = \pm(\sqrt{X_{11} X_{22}} / X_{12}^2)$ is obtained.

The reactances $X_{11}$ and $X_{22}$ have the same signs, either positive or negative. Therefore, two cases are possible. When $X_{11}$ and $X_{22}$ are both negative numbers, $\theta = n \cdot \pi + \cos^{-1}(\sqrt{X_{11} X_{22}} / X_{12}^2)$, while if $X_{11}$ and $X_{22}$ are both positive numbers, $\theta = n \cdot \pi - \cos^{-1}(\sqrt{X_{11} X_{22}} / X_{12}^2)$, where $n$ is an odd or even number, chosen such that the phase angles of the transmission $S$-parameters for the circuit shown in Fig. 1(b) match the values obtained by measurements.

For both cases, the characteristic impedances $Z_{c1}$ and $Z_{c2}$ can be derived from expressions (1) and (2), so that: $Z_{c1} = -Z_o X_{11} \tan(\theta)$ and $Z_{c2} = -Z_o X_{22} \tan(\theta)$.

If $A_{in}$ is the $ABCD$ matrix of the input circuit $C_{in}$, this matrix can be found with Mathcad [23], as solution of the matrix equation $A_{\text{thru}} = A_{in} A_x A_{in}$, where $A_x$ is the $ABCD$ matrix obtained from the impedance matrix $Z_x$.

For the second set of measurements, the waveguide flanges of the two transitions are connected to each other with a shorting metal plate inserted between them, as shown in Fig. 2(a) (short-circuit standard). For the resulting two-port structure, the reflection scattering parameters $S_{11}$ and $S_{22}$ at the coaxial ports #1 and #2, respectively, are measured. The equivalent circuits of the short-ended transitions $T1$ and $T2$ are presented in Figs. 2(b), (c), where $\theta_1$ and $\theta_2$ must be determined so that $\theta = \theta_1 + \theta_2$, while $Z_s$ is the equivalent impedance of the shorting metal plate.

Knowing $S_{11}$ and $S_{22}$, the input impedances of the two short-ended transitions can be computed using the formulas: $Z_{in,1} = Z_c(1 + S_{11}) / (1 - S_{11})$ and $Z_{in,2} = Z_c(1 + S_{22}) / (1 - S_{22})$, respectively (see Chapter 4 of [24]).

If the $ABCD$ matrix $A_{in}$ is known, the characteristic impedances $Z_{c1}$ and $Z_{c2}$, as well as $Z_{in,1}$ and $Z_{in,2}$, are calculated as shown before, and the values of the reflection coefficients $\Gamma_1$ and $\Gamma_2$ from Figs. 2(b), (c) can also be calculated.
In order to compute $\theta_1$ and $\theta_2$, from Figs. 2(b), (c), we can write: $\Gamma_1 = \Gamma_s \cdot \exp(-j2\theta_1)$ and $\Gamma_2 = \Gamma_s \cdot \exp(-j2\theta_2)$ (see Chapter 2 of [24]). Assuming $|\Gamma_1| = |\Gamma_2|$ (lossless transmission lines), it is obtained that $\theta_1 = \theta/2 + \Delta\theta/2$ and $\theta_2 = \theta/2 - \Delta\theta/2$, where $\Delta\theta = \theta_1 - \theta_2 = (\varphi_{T2} - \varphi_{T1})/2$, while $\varphi_{T1}$ and $\varphi_{T2}$ are the phase angles of $\Gamma_1$ and $\Gamma_2$, respectively.

The $ABCD$ matrices for the coaxial to waveguide transitions $T1$ and $T2$ can be computed as follows:

$$A_{T1} = A_{in} \cdot \begin{bmatrix} 0 & jZ_{cl} \\ j/Z_{cl} & 0 \end{bmatrix} \cdot \begin{bmatrix} \cos(\theta_1) & jZ_o \sin(\theta_1) \\ j \sin(\theta_1)/Z_o & \cos(\theta_1) \end{bmatrix}$$  \hspace{1cm} (4a)$$

and

$$A_{T2} = \begin{bmatrix} \cos(\theta_2) & jZ_o \sin(\theta_2) \\ j \sin(\theta_2)/Z_o & \cos(\theta_2) \end{bmatrix} \cdot \begin{bmatrix} 0 & jZ_{c2} \\ j/Z_{c2} & 0 \end{bmatrix} \cdot A_{in}$$  \hspace{1cm} (4b)$$

respectively.

Once the $ABCD$ matrices of the coaxial to waveguide transitions are known, these transitions can be de-embedded, and the $ABCD$ matrix, as well as the $S$-parameter matrix of the waveguide device connected between the transitions, can be found out.

### 3. COMPARISON BETWEEN THE EXPERIMENTAL AND SIMULATED RESULTS

The measured $S$-parameters for the thru and short-circuit standards were compared with the $S$-parameters obtained by using the matrices $ABCD$ of transitions $T1$ and $T2$, which can be determined as shown in the previous section.

In this paper, transitions from $50 \Omega$ coaxial connector (2.92 mm — Female) to WR-28 waveguide from Pasternack are used (the inner sizes of the cross-section waveguide ports are $a = 7.111$ mm and $b = 3.556$ mm). All measurements were performed using Anritsu MS46122A-040 VNA.

For the thru setup, the magnitude and phase of the $S$-parameters measured at the $50 \Omega$ coaxial ports are compared to the simulated ones that were computed from the $ABCD$ matrix obtained by multiplying $A_{T1}$ and $A_{T2}$ matrices given by (4a) and (4b), respectively. The results are presented in Fig. 3. Since the elements of the equivalent circuit shown in Fig. 1(b) were computed so as to match the measured $S$-parameters, no differences can be observed between the experimental values and those obtained for the equivalent circuit.

When the transitions $T1$ and $T2$ are short-circuited at the waveguide ports (short-circuit standard), the reflection coefficients $S_{11}$ and $S_{22}$ at the $50 \Omega$ coaxial ports can also be computed from the $ABCD$ matrices (4a) and (4b), respectively. A comparison between these simulated $S$-parameters and those obtained from measurements is presented in Fig. 4. Differences less than 0.05 can be observed between

![Figure 3](image-url)

**Figure 3.** Measured and simulated (a) magnitude and (b) phase of the $S$-parameters, for the thru setup.
Figure 4. Measured and simulated (a) magnitude and (b) phase of the input reflection coefficients, when the waveguide ports of the coaxial to waveguide transitions are short-circuited.

Figure 5. Simulated return-loss versus frequency computed at the 50 coaxial ports, when the waveguide ports are loaded by the wave impedance of the dominant mode $TE_{10}$.

the experimental and simulated magnitude values of the reflection coefficients $S_{11}$ and $S_{22}$. These differences are the result of the assumption that transitions have the same losses. The differences between the simulated and experimental phase values of these reflection coefficients are less than 5 degrees.

Based on the $ABCD$ matrices determined for transitions, the return loss values at the 50 Ω coaxial ports were also computed, for the situation when the waveguide ports are loaded by the wave impedance $Z_o$ of the dominant mode $TE_{10}$. The results are presented in Fig. 5. The VSWR values for both transitions are smaller than 1.25, which is the maximum value provided by the manufacturer for frequencies between 26.5 and 40 GHz.

4. APPLICATION TO THE DETERMINATION OF THE COMPLEX RELATIVE PERMITTIVITY USING THE T/R METHOD

The unterminating method presented in this paper was applied to de-embed the coaxial to waveguide transitions in an experimental setup used to determine the complex relative permittivity of three dielectric materials, by following the NRW transmission/reflection (T/R) method [15–17].

The experimental setup is presented in Fig. 6, where a rectangular metallic waveguide section (WS) of length $L_{WS} = 25$ mm is inserted between two coaxial to waveguide transitions, $T1$ and $T2$. The rectangular waveguides of the transitions and WS have the same inner sizes, the width $a$ and height $b$. 
To use the NRW method, the scattering parameters for the hollow WS and the WS loaded with the dielectric sample must be known.

Three dielectric samples made of ABS, PLA, and PTFE materials were measured. The ABS and PLA samples were prepared by using a 3D printer. All three dielectric samples have rectangular cross-sections of width $a$ and height $b$.

The relative uncertainty in complex relative permittivity due to the uncertainty of the measured scattering parameters has low values if the ratio between the sample length and the guided wavelength in the sample is greater than 1 [17]. Taking into account this design condition, the length $L$ for each sample was chosen to be equal to 15 mm.

The measured scattering matrices at ports #1 and #2 with and without dielectric sample were transformed into the $ABCD$ matrices $A_1$ and $A_2$, respectively. Thus, if $A_1^T$ and $A_2^T$ are computed with (4a) and (4b), the $ABCD$ matrices of the WS with and without dielectric sample can be found out as

$$A_x = A_1^T A_1 A_2^T A_2$$
and

$$A_y = A_1^T A_1 A_2^T A_2 + A_1^T A_2^T A_2^T A_2$$, respectively. Finally, the scattering parameter of the WS with and without dielectric sample, $S_x$ and $S_y$, respectively, can be found out (see Chapter 4 of [24]).

Combining Equations (8)–(11) and (16) given in [17], the real and imaginary parts of the complex relative permittivity of the dielectric sample, $\varepsilon_r = \varepsilon'_r - j \varepsilon''_r$, can be expressed as:

$$\varepsilon'_r = \left(\frac{c_0}{2\pi f}\right)^2 \left\{ \left(\frac{\pi}{a}\right)^2 - \left[\text{Re}(\gamma)\right]^2 + \left[\text{Im}(\gamma)\right]^2 \right\}$$
and

$$\varepsilon''_r = -2\text{Re}(\gamma)\text{Im}(\gamma) \left(\frac{c_0}{2\pi f}\right)^2,$$

where $\gamma$ is the propagation constant in the dielectric sample, a complex number with the real and imaginary parts given by $\text{Re}(\gamma) = -\ln|z|/L$ and $\text{Im}(\gamma) = -(\varphi_z - 2m\pi)/L$, respectively, while $\varphi_z$ is the phase angle of the complex number $z$, and $m$ is an integer positive number chosen so that the function $\text{Im}(\gamma)$ is continuous versus the frequency.

The complex number $z$ is the solution of the following second order equation, for which $\text{Re}(\gamma) > 0$:

$$z^2 - z \left(\frac{S_{21}^y}{S_{22}^x}\right) \left\{ 1 + (S_{12}^x S_{21}^y - S_{11}^x S_{22}^y) \exp \left[2\gamma_0(L_{WS} - L)\right]\right\} \exp(\gamma_0 L) + 1 = 0,$$

where $S_{ij}^x$ and $S_{ij}^y$ (i and j are equal to 1 or 2) are the $ij$ elements of the matrices $S^x$ and $S^y$, respectively, while $\gamma_0 = j\sqrt{(2\pi f/c_0)^2 - (\pi/a)^2}$ is the propagation constant into the hollow WS, $f$ the frequency, and $c_0$ the speed of light.

The numerical results obtained for the real and imaginary parts of the complex relative permittivity are presented in Fig. 7. In this figure, the solid lines represent the average values obtained for these parameters, for each material. The variation of the real part of $\varepsilon_r$ versus the frequency is within $\pm 0.06$ around the average value, for each material. On the other hand, the values obtained for the imaginary part of $\varepsilon_r$ show large differences around the average values.

The sources of errors in the determination of $\varepsilon_r$ are due to the uncertainty in the measured scattering parameters at the VNA coaxial reference ports and de-embedding process of the coaxial to waveguide transitions. Both sources of errors contribute to the uncertainty in the scattering parameters that are
Figure 7. (a) Real part and (b) imaginary part of the complex relative permittivity versus the frequency, for ABS, PLA and PTFE materials measured in this paper by using the NRW method and the proposed unterminated method for de-embedding the coaxial to waveguide transitions.

obtained at the waveguide ports after de-embedding the coaxial to waveguide transitions. A detailed analysis of the uncertainty of $\varepsilon_r$ in the scattering parameters by taking into account the intervening transitions is beyond the scope of this paper, but a short uncertainty analysis to explain the dispersion of the measured real and imaginary parts of $\varepsilon_r$ around the average values is presented as follows.

The relative uncertainty in $\varepsilon_r$ due to the measured transmission and reflection scattering parameters at the waveguide ports can be preliminarily evaluated using the relationships presented in [17], for the measurement uncertainties of the VNA at the coaxial ports. The effect of the unterminating errors could be evaluated by overestimating the measurement uncertainties of the VNA. In this way, it was observed that the uncertainties in the scattering parameters has an important effect on the imaginary part of $\varepsilon_r$

Table 1. Comparison with results reported by other authors for the complex relative permittivity of the ABS, PLA and PTFE materials.

<table>
<thead>
<tr>
<th></th>
<th>Ref.</th>
<th>$\varepsilon_r$</th>
<th>$\varepsilon_r''$</th>
<th>Frequency range</th>
<th>Experimental Method</th>
</tr>
</thead>
<tbody>
<tr>
<td>ABS</td>
<td>[19]</td>
<td>2.6</td>
<td>0.014</td>
<td>1–10 GHz</td>
<td>T/R, coaxial</td>
</tr>
<tr>
<td></td>
<td>[20]</td>
<td>2.4</td>
<td>0.013</td>
<td>30–50 GHz</td>
<td>T/R, coaxial</td>
</tr>
<tr>
<td></td>
<td>[21]</td>
<td>2.57</td>
<td>0.035</td>
<td>8.2–11 GHz</td>
<td>T/R, waveguide</td>
</tr>
<tr>
<td></td>
<td>[22]</td>
<td>2.6</td>
<td>-</td>
<td>12–18 GHz</td>
<td>T/R, waveguide</td>
</tr>
<tr>
<td></td>
<td>[25]</td>
<td>2.75</td>
<td>0.019</td>
<td>~ 11 GHz</td>
<td>Dielectric resonator</td>
</tr>
<tr>
<td>This work</td>
<td></td>
<td>2.61</td>
<td>0.019</td>
<td>25–40 GHz</td>
<td>T/R, waveguide</td>
</tr>
<tr>
<td>PLA</td>
<td>[19]</td>
<td>2.71</td>
<td>0.017</td>
<td>1–10 GHz</td>
<td>T/R, coaxial</td>
</tr>
<tr>
<td></td>
<td>[20]</td>
<td>2.57</td>
<td>0.024</td>
<td>30–50 GHz</td>
<td>T/R, coaxial</td>
</tr>
<tr>
<td></td>
<td>[26]</td>
<td>2.75</td>
<td>0.033</td>
<td>40 GHz</td>
<td>R, waveguide</td>
</tr>
<tr>
<td></td>
<td>[27]</td>
<td>2.75</td>
<td>0.041</td>
<td>2–18 GHz</td>
<td>T/R, coaxial</td>
</tr>
<tr>
<td>This work</td>
<td></td>
<td>2.75</td>
<td>0.04</td>
<td>25–40 GHz</td>
<td>T/R, waveguide</td>
</tr>
<tr>
<td>PTFE</td>
<td>[20]</td>
<td>2.03</td>
<td>0.00061</td>
<td>30–50 GHz</td>
<td>T/R, coaxial</td>
</tr>
<tr>
<td></td>
<td>[28]</td>
<td>2.08</td>
<td>0.00066</td>
<td>19.82 GHz</td>
<td>Resonant waveguide</td>
</tr>
<tr>
<td></td>
<td>[29]</td>
<td>2.071</td>
<td>0.00097</td>
<td>60.291 GHz</td>
<td>Open resonator</td>
</tr>
<tr>
<td>This work</td>
<td></td>
<td>2.078</td>
<td>0.00076</td>
<td>25–40 GHz</td>
<td>T/R, waveguide</td>
</tr>
</tbody>
</table>
and a small effect on the real part of \( \varepsilon_r \). Numerical results showed that the relative uncertainty due to the transmission and reflection scattering parameters is smaller than \( 10^{-2} \) for the real part of \( \varepsilon_r \), so that the uncertainty in the real part of \( \varepsilon_r \) is small compared to its average value. This could explain why the measured values of the real part of \( \varepsilon_r \) are close to the average values. In contrast, the relative uncertainty in the imaginary part of \( \varepsilon_r \) due to the scattering parameters is higher (\( \sim 0.1-1 \)), so that any increase of the uncertainty in the scattering parameters at the waveguide ports due to the errors of the unterminating technique has a significant effect on the imaginary part value of \( \varepsilon_r \). For example, increasing the uncertainty in the magnitude of the reflection coefficients by 0.05, the uncertainties in the imaginary part value of \( \varepsilon_r \) could be comparable to the average value, for all three materials.

A comparison between the average values obtained in this paper for the real and imaginary parts of \( \varepsilon_r \) and those reported in other references is presented in Table 1, for all three materials. As observed, the average values of both real and imaginary parts of \( \varepsilon_r \) are similar to the values measured by other authors, for all materials analyzed in this paper.

5. CONCLUSION

A simple noniterative unterminating method is proposed for the coaxial to waveguide transition. This method consists of only two measurements of scattering parameters, both performed by using a VNA connected to the coaxial ports of the transitions. Based on this method, the \( ABCD \) matrices of the coaxial to waveguide transitions have been obtained. The proposed unterminating method was validated in two steps. Firstly, the measured scattering parameters for the thru and short-circuit standards were compared with the simulated scattering parameters obtained from the \( ABCD \) matrices of the transitions. No differences between the experimental and simulated scatterings has been observed for the thru standard. For the short-circuit standard, some differences occur for the magnitudes of the input reflection coefficients, while the differences between the experimental and simulated phase values of these reflection coefficients are very small.

To complete the validation of the proposed unterminating method, the complex relative permittivity using the NRW method for a waveguide measurement setup was determined for three dielectric materials, and the results were compared with those reported in other references. For this task, first of all, the coaxial to waveguide transitions were de-embedded by using the \( ABCD \) matrices of the transitions found in this paper. The average values obtained for the real and imaginary parts of the complex relative permittivity are in good agreement with those reported by other authors, for all three dielectric materials.

The experiments were performed in the 25–40 GHz frequency band using commercial coaxial to waveguide transitions, but the proposed unterminating method can also be used in any other frequency band.

REFERENCES


23. Mathcad — *User’s guide* (MathSoft, Inc.).


